

LF444QML Quad Low Power JFET Input Operational Amplifier

Check for Samples: [LF444QML](#)

FEATURES

- 1/4 supply current of a LM148: 250 μ A/Amplifier (max)
- Low input bias current: 100 pA (max)
- High gain bandwidth: 1 MHz
- High slew rate: 1 V/ μ s
- Low noise voltage for low power 35 nV/ $\sqrt{\text{Hz}}$
- Low input noise current 0.01 pA/ $\sqrt{\text{Hz}}$
- High input impedance: $10^{12}\Omega$
- High gain, $V_O = \pm 10\text{V}$, $R_L = 10\text{k}\Omega$: 25K (min)

DESCRIPTION

The LF444 quad low power operational amplifier provides many of the same AC characteristics as the industry standard LM148 while greatly improving the DC characteristics of the LM148. The amplifier has the same bandwidth, slew rate, and gain (10 k Ω load) as the LM148 and only draws one fourth the supply current of the LM148. In addition the well matched high voltage JFET input devices of the LF444 reduce the input bias and offset currents by a factor of 10,000 over the LM148. The LF444 also has a very low equivalent input noise voltage for a low power amplifier.

The LF444 is pin compatible with the LM148 allowing an immediate 4 times reduction in power drain in many applications. The LF444 should be used wherever low power dissipation and good electrical characteristics are the major considerations.

Connection Diagram

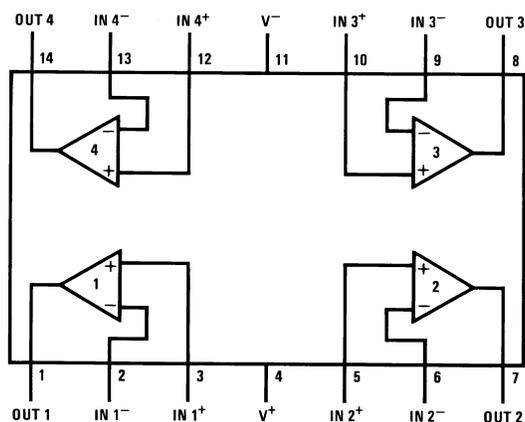


Figure 1. Dual-In-Line Package Top View



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Simplified Schematic

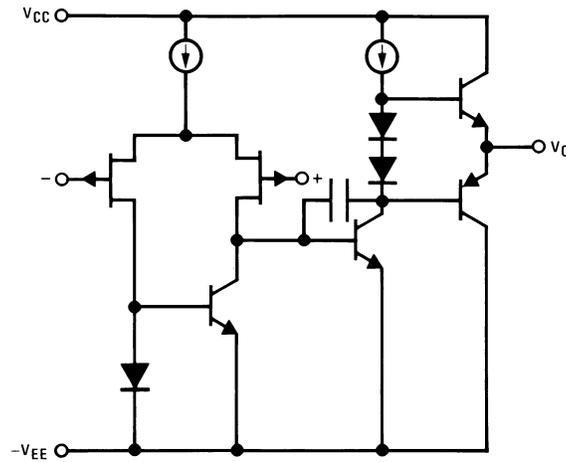


Figure 2. 1/4 Quad

Detailed Schematic

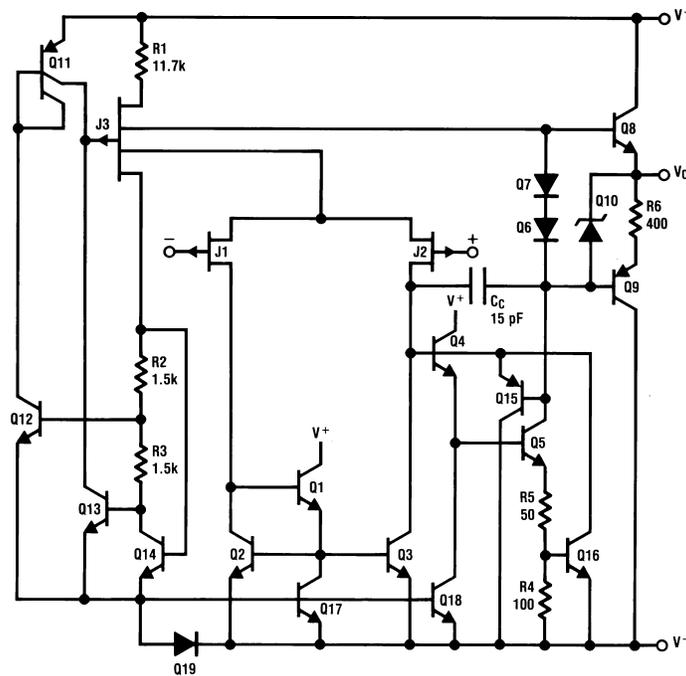


Figure 3. 1/4 Quad



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾

Supply Voltage	±18V
Differential Input Voltage	±30V
Input Voltage Range ⁽²⁾	±15V
Output Short Circuit Duration ⁽³⁾	Continuous
Power Dissipation ^{(4), (5)}	900 mW
T _{Jmax}	150°C
θ _{JA} (Typical)	100°C/W
Operating Temperature Range	-55°C ≤ T _A ≤ 125°C
Storage Temperature Range	-65°C ≤ T _A ≤ 150°C
ESD Tolerance ⁽⁶⁾	Rating to be determined

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) Unless otherwise specified the absolute maximum negative input voltage is equal to the negative power supply voltage.
- (3) Any of the amplifier outputs can be shorted to ground indefinitely, however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.
- (4) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is P_{Dmax} = (T_{Jmax} - T_A)/θ_{JA} or the number given in the Absolute Maximum Ratings, whichever is lower.
- (5) Max. Power Dissipation is defined by the package characteristics. Operating the part near the Max. Power Dissipation may cause the part to operate outside guaranteed limits.
- (6) Human body model, 1.5 kΩ in series with 100 pF.

Quality Conformance Inspection
Table 1. Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp (°C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55
12	Settling time at	+25
13	Settling time at	+125
14	Settling time at	-55

LF444 Electrical Characteristics DC Parameters

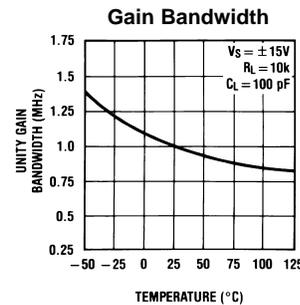
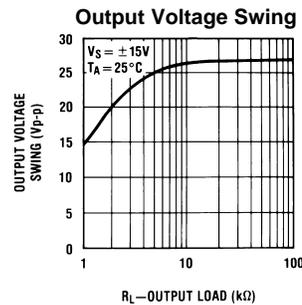
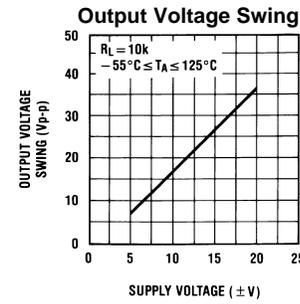
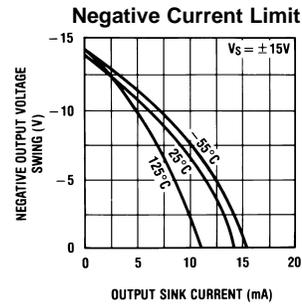
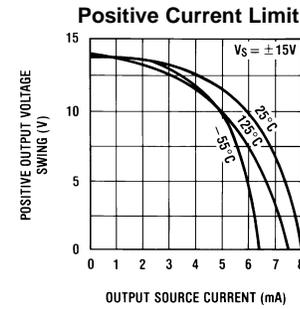
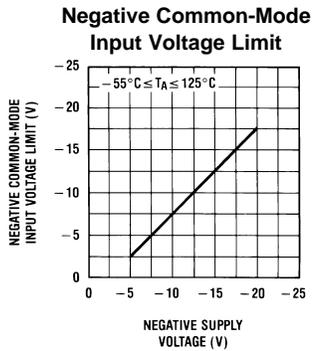
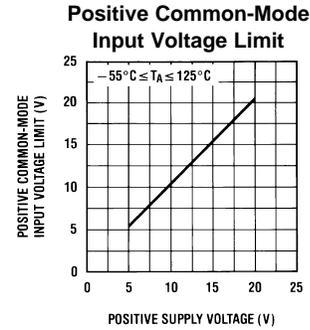
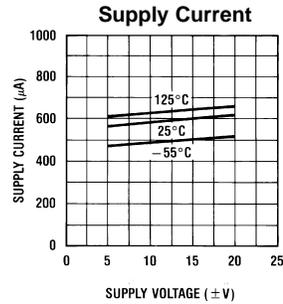
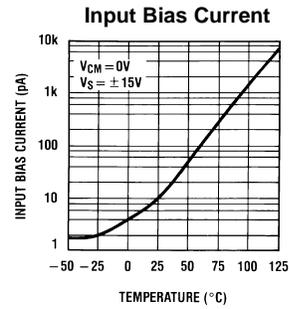
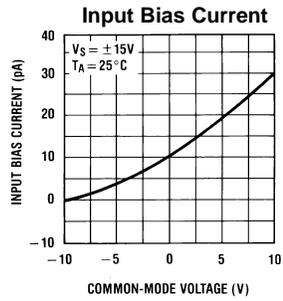
The following conditions apply, unless otherwise specified. $V_S = \pm 15V$, $V_{CM} = 0V$, $R_S = 0\Omega$, $R_L = 0\Omega$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-groups
V_{IO}	Input Offset Voltage	$R_S = 10K\Omega$		-10	10	mV	1
				-14	14	mV	2, 3
I_{IO}	Input Offset Current	$R_L = 10K\Omega$		-0.05	0.05	nA	1
				-10	10	nA	2
$+I_{IB}$	Input Bias Current	$R_L = 10K\Omega$		-0.10	0.10	nA	1
				-20	20	nA	2
$-I_{IB}$	Input Bias Current	$R_L = 10K\Omega$		-0.10	0.10	nA	1
				-20	20	nA	2
$+A_{VS}$	Large Signal Voltage Gain	$V_O = 0$ to $+10V$, $R_L = 10K\Omega$, $R_S = 10K\Omega$	(1)	25		V/mV	1
				15		V/mV	2, 3
$-A_{VS}$	Large Signal Voltage Gain	$V_O = 0$ to $-10V$, $R_L = 10K\Omega$, $R_S = 10K\Omega$	(1)	25		V/mV	1
				15		V/mV	2, 3
$+V_O$	Output Voltage Swing	$R_L = 10K\Omega$, $V_I = +1V$		12		V	1, 2, 3
$-V_O$	Output Voltage Swing	$R_L = 10K\Omega$, $V_I = -1V$			-12	V	1, 2, 3
V_{CM}	Input Common Mode Voltage Range		(2)	9	-9	V	1, 2, 3
CMRR	Common Mode Rejection Ratio	$R_S = 10K\Omega$, $V_{CM} = \pm 9V$		70		dB	1, 2, 3
PSRR+	Power Supply Rejection Ratio	$V_S = \pm 15V$ to $V_S = \pm 6V$		70		dB	1, 2, 3
PSRR-	Power Supply Rejection Ratio	$V_S = \pm 15V$ to $V_S = \pm 6V$		70		dB	1, 2, 3
I_S	Supply Current				1.0	mA	1, 2, 3
$+I_{OS}$	Output Short Circuit Current	$V_I = 1V$		-3.0	-20	mA	1
				-3.0	-40	mA	2, 3
$-I_{OS}$	Output Short Circuit Current	$V_I = -1V$		3.0	20	mA	1
				3.0	40	mA	2, 3

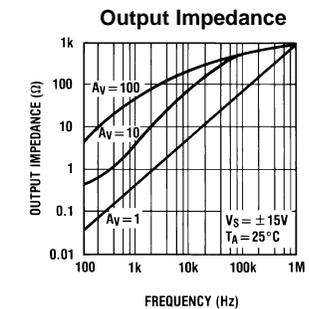
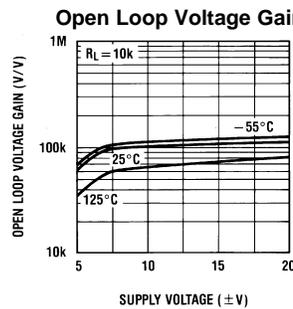
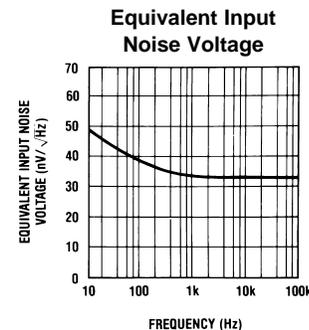
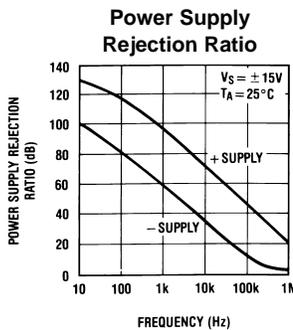
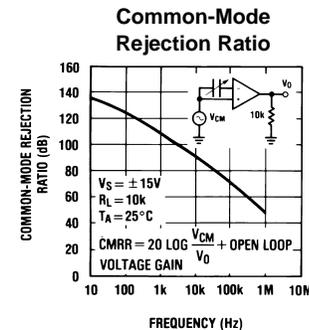
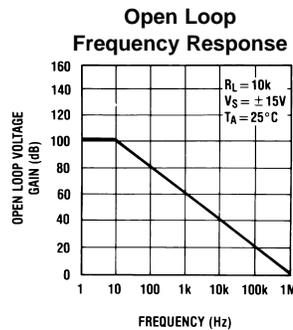
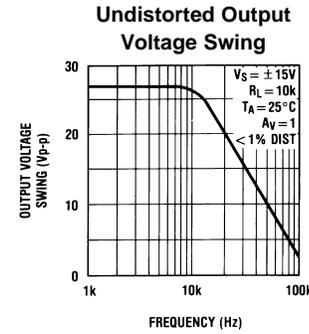
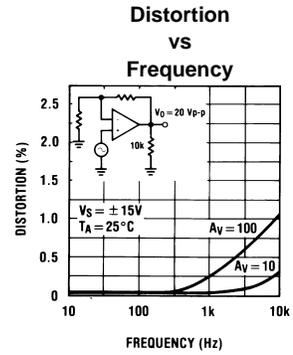
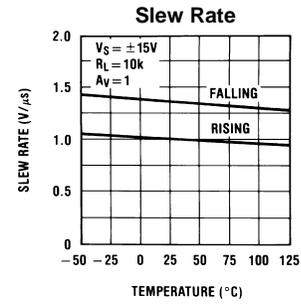
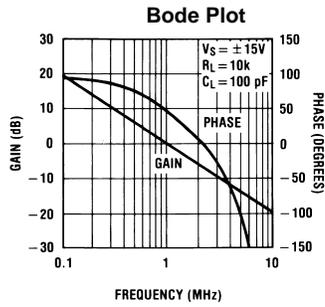
(1) Datalog in K = V/mV.

(2) Parameter tested go-no-go only. Guaranteed by the CMRR test.

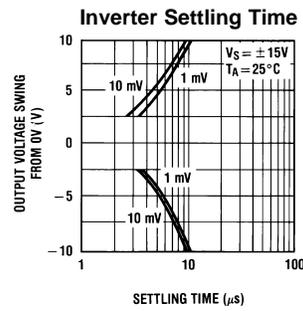
Typical Performance Characteristics



Typical Performance Characteristics (continued)



Typical Performance Characteristics (continued)



PULSE RESPONSE – $R_L = 10\text{ k}\Omega$, $C_L = 10\text{ pF}$

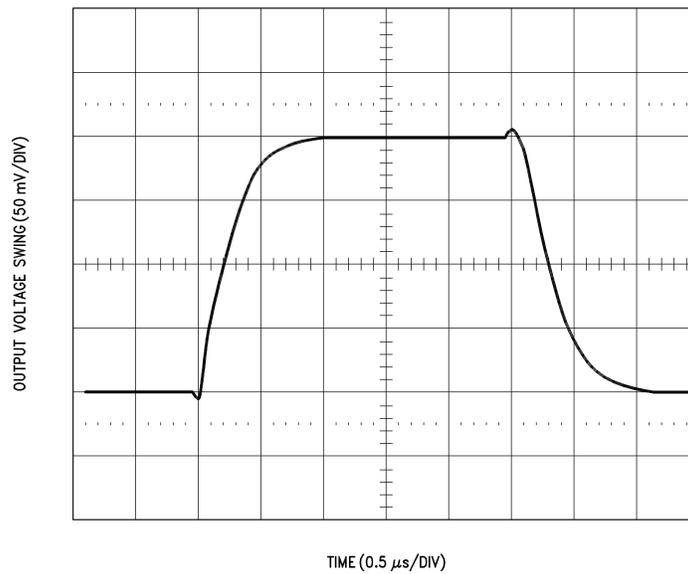


Figure 4. Small Signal Inverting

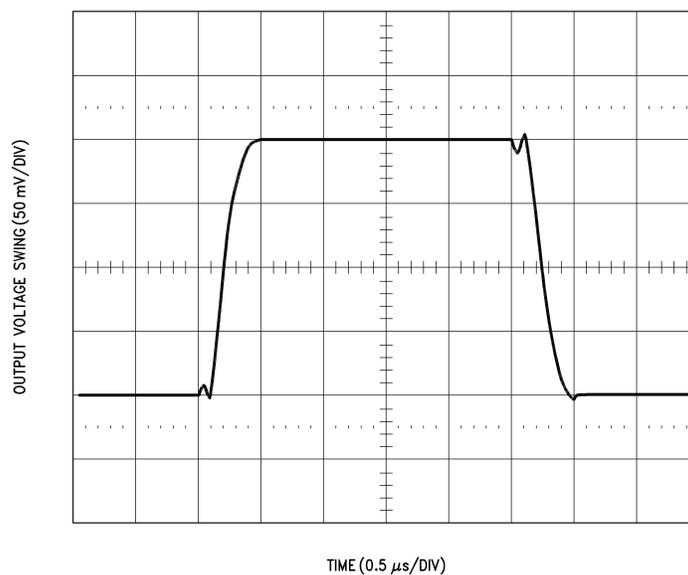


Figure 5. Small Signal Non-Inverting

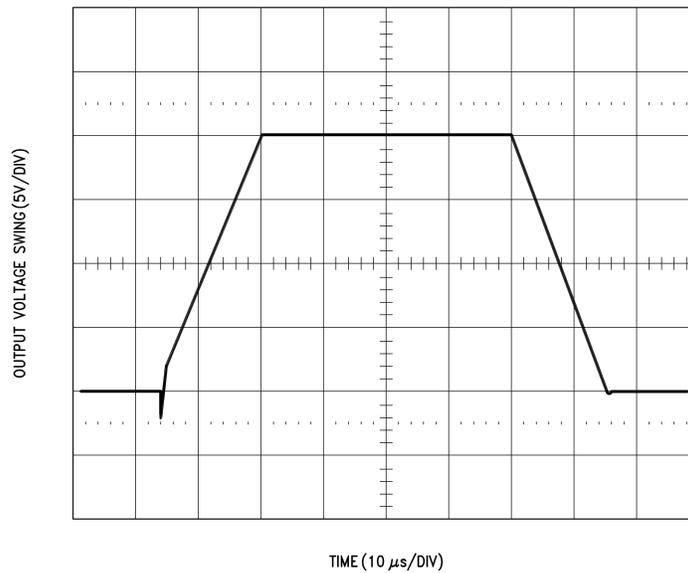


Figure 6. Large Signal Inverting

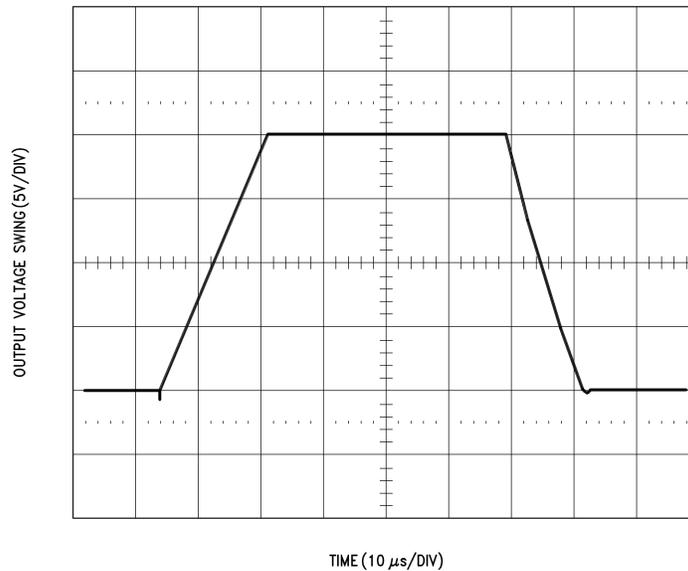


Figure 7. Large Signal Non-Inverting

Application Hints

This device is a quad low power op amp with JFET input devices (BI-FET™). These JFETs have large reverse breakdown voltages from gate to source and drain eliminating the need for clamps across the inputs. Therefore, large differential input voltages can easily be accommodated without a large increase in input current. The maximum differential input voltage is independent of the supply voltages. However, neither of the input voltages should be allowed to exceed the negative supply as this will cause large currents to flow which can result in a destroyed unit.

Exceeding the negative common-mode limit on either input will force the output to a high state, potentially causing a reversal of phase to the output. Exceeding the negative common-mode limit on both inputs will force the amplifier output to a high state. In neither case does a latch occur since raising the input back within the common-mode range again puts the input stage and thus the amplifier in a normal operating mode.

Exceeding the positive common-mode limit on a single input will not change the phase of the output; however, if both inputs exceed the limit, the output of the amplifier will be forced to a high state.

The amplifiers will operate with a common-mode input voltage equal to the positive supply; however, the gain bandwidth and slew rate may be decreased in this condition. When the negative common-mode voltage swings to within 3V of the negative supply, an increase in input offset voltage may occur.

Each amplifier is individually biased to allow normal circuit operation with power supplies of $\pm 3.0V$. Supply voltages less than these may degrade the common-mode rejection and restrict the output voltage swing.

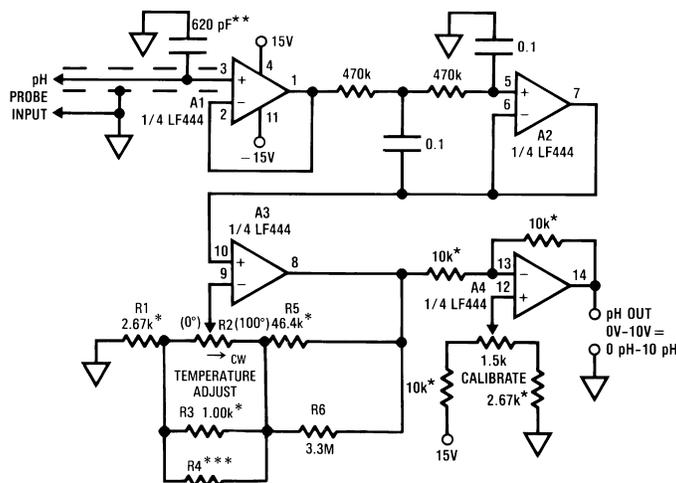
The amplifiers will drive a 10 k Ω load resistance to $\pm 10V$ over the full temperature range. If the amplifier is forced to drive heavier load currents, however, an increase in input offset voltage may occur on the negative voltage swing and finally reach an active current limit on both positive and negative swings.

Precautions should be taken to ensure that the power supply for the integrated circuit never becomes reversed in polarity or that the unit is not inadvertently installed backwards in a socket as an unlimited current surge through the resulting forward diode within the IC could cause fusing of the internal conductors and result in a destroyed unit.

As with most amplifiers, care should be taken with lead dress, component placement and supply decoupling in order to ensure stability. For example, resistors from the output to an input should be placed with the body close to the input to minimize “pick-up” and maximize the frequency of the feedback pole by minimizing the capacitance from the input to ground.

A feedback pole is created when the feedback around any amplifier is resistive. The parallel resistance and capacitance from the input of the device (usually the inverting input) to AC ground set the frequency of the pole. In many instances the frequency of this pole is much greater than the expected 3 dB frequency of the closed loop gain and consequently there is negligible effect on stability margin. However, if the feedback pole is less than approximately 6 times the expected 3 dB frequency a lead capacitor should be placed from the output to the input of the op amp. The value of the added capacitor should be such that the RC time constant of this capacitor and the resistance it parallels is greater than or equal to the original feedback pole time constant.

Typical Application



***For R2 = 50k Ω , R4 = 330k $\pm 1\%$

For R2 = 100k, R4 = 75k $\pm 1\%$

For R2 = 200k, R4 = 56k $\pm 1\%$

**Polystyrene

*Film resistor type RN60C

To calibrate, insert probe in pH =7 solution. Set the “TEMPERATURE ADJUST” pot, R2, to correspond to the solution temperature: full clockwise for 0°C, and proportionately for intermediate temperatures, using a turns-counting dial.

Then set “CALIBRATE” pot so output reads 7V.

Typical probe = Ingold Electrodes #465-35

Figure 8. pH Probe Amplifier/Temperature Compensator

Table 2. Revision History

Date Released	Revision	Section	Changes
12/16/2010	A	New release to corporate format	1 MDS datasheet converted to standard corporate format. MDS MNLF444M-X Rev 0AL will be archived.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Samples (Requires Login)
LF444MD/883	ACTIVE	CDIP SB	NAK	14	25	TBD	POST-PLATE	Level-1-NA-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

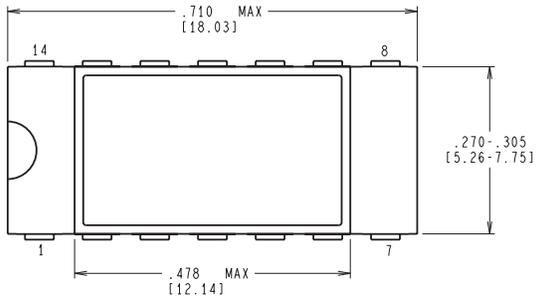
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

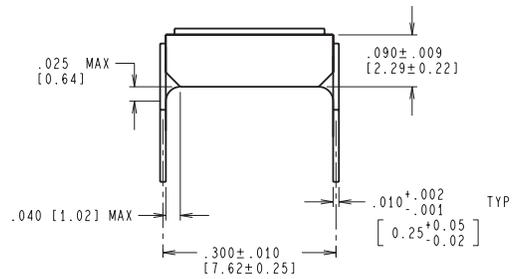
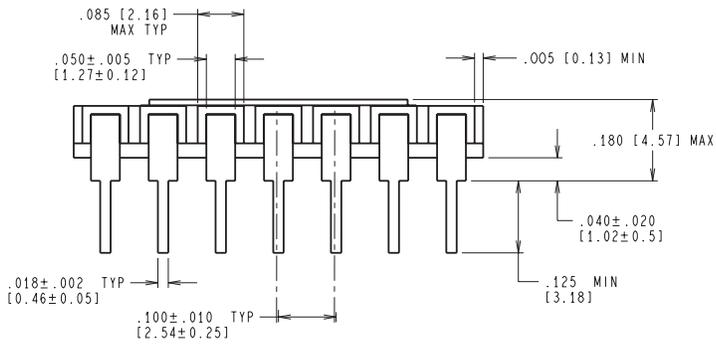
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